OPE5159UY

The **OPE5159UY** is AlGaInP ultra bright light emitting diode that is designed for ultra brightness and excellent reliability. This device is optimized for efficiency at peak wavelength 591nm.

This device is packaged T13/4 plastic package and has medium beam angle with lensed package and cup frame.

FEATURES

- Ultra brightness
- Peak wavelength : 591nm
- Medium beam angle
- Excellent reliability
- Available for pulse operating

APPLICATIONS

- PIXEL cluster
- LED Dot Matrix
- Traffic signal
- Display signboard

STORAGE

- Condition: 5°C~35°C,R.H.60%
- Terms: within 3 months from production date
- Remark : Once the package is opened, the products should be used within a day. Otherwise, it should be keeping in a damp proof box with desiccants.
- * Please take proper steps in order to secure reliability and safety in required conditions and environments for this device.

MAXIMUM RATINGS

 $(Ta=25^{\circ}C)$

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Item	Symbol	Rating	Unit	
Power dissipation	P_{D}	40	mW	
Forward current	I_F	30	mA	
Pulse forward current *1	I_{FP}	50	mA	
Reverse voltage	V_R	4	V	
Operating temp.	Topr.	-25~ +85	°C	
Soldering temp. *2	Tsol.	260.	°C	

^{*1.}Duty ratio = 1/100, pulse width=0.1ms.

ELECTRO-OPTICAL CHARACTERISTICS

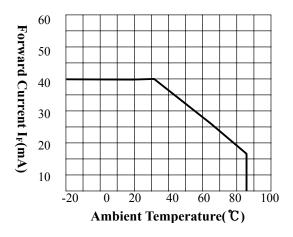
(Ta=25°C)

Item	Symbol	Conditions	Min.	Тур.	Max.	Unit
Luminous intensity	Iv	$I_F=20$ mA				mcd
Peak emission wavelength	λ_{p}	$I_F=20$ mA		591		nm
Spectral bandwidth	Δλ	$I_F=20$ mA		15		nm
Forward voltage	$V_{\rm F}$	$I_F=20$ mA		2.0	2.4	V
Reverse current	I_R	$V_R=4V$			100	μΑ
Half angle	ΔΘ	I_F =20mA		±10		deg.

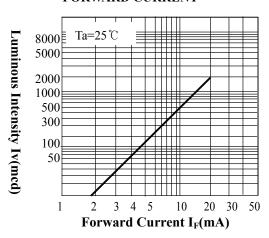
DIMENSIONS (Unit: mm)

^{*2.}Lead soldering temperature (2mm from case for 5sec.).

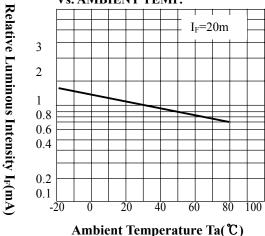
FORWARD CURRENT Vs. AMBIENT TEMP



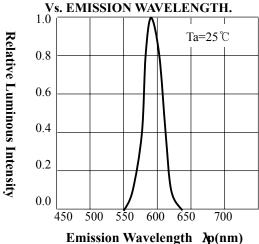
• LUMINOUS INTENSITY Vs. FORWARD CURRENT



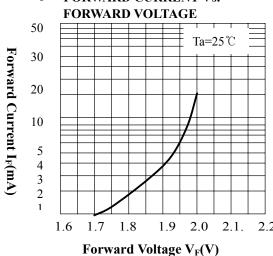
• RELATIVE LUMINOUS INTENSITY Vs. AMBIENT TEMP.



• RELATIVE LUMINOUS INTENSITY



• FORWARD CURRENT Vs.



• RELATIVE LUMINOUS INTENSITY Vs. ANGULAR DIAPLACEMENT

